Dual Nano-power Open Drain Output Comparator

The NCS3402 is a nano-power comparator consuming only 470 nA per channel supply current, which make this device ideal for battery power and wireless handset applications.

The NCS3402 has a minimum operating supply voltage of 2.7 V over the extended industrial temperature range ($T_A = -40^{\circ}\text{C}$ to 125°C), while having an input common-mode range of -0.1 to $V_{DD} + 5$ V.

The ultra low supply current makes the NCS3402 an ideal choice for battery powered and portable applications where quiescent current is the primary concern. Reverse battery protection guards the amplifier from an over-current condition due to improper battery installation. For harsh environments, the inputs can be taken 5 V above the positive supply rail without damage to the device.

Features

- Low Supply Current: 470 nA/Per Channel
 - Input Common-Mode Range exceeds the rails
 - \bullet -0.1 V to VDD + 5 V
- Supply Voltage Range: 2.7 V to 16 V
- Reverse Battery Protection Up to 18 V
- Open Drain CMOS Output Stage
- Specified Temperature Range
 - −40°C to 125°C
- This is a Pb-Free Device

Typical Applications

- Voltage Sense Circuit
- PSU Monitoring Circuit
- Wireless Handsets
- Portable Medical Equipment



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MARKING DIAGRAMS



W

SOIC-8 **D SUFFIX CASE 751**



= Assembly Location

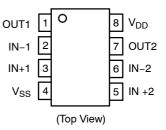
= Wafer Lot 1 Υ = Year

= Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

PIN FUNCTION DESCRIPTION

| Pin No. | Pin Name | Description |
|---------|-----------------|-------------------------------|
| 1 | OUT1 | Channel 1 Output |
| 2 | IN-1 | Channel 1 Inverting Input |
| 3 | IN+2 | Channel 2 Non-Inverting Input |
| 4 | V _{SS} | Negative Power Supply |
| 5 | IN+2 | Channel 2 Non-Inverting Input |
| 6 | IN-2 | Channel 2 Inverting Input |
| 7 | OUT2 | Channel 2 Output |
| 8 | V _{DD} | Positive Power Supply |

ABSOLUTE MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|------------------|--------------------------|------|
| Supply Voltage | V _{DD} | 17 | V |
| Differential Input Voltage | V _{ID} | ±20 | V |
| Input Voltage Range (Notes 1 and 2) | V _{IN} | 0 to V _{CC} + 5 | V |
| Input Current Range | I _{IN} | ±10 | mA |
| Output Current Range | lo | ±10 | mA |
| Operating Free-Air Temperature Range | T _A | -40 to +125 | °C |
| Maximum Junction Temperature | T _J | 150 | °C |
| Storage Temperature Range | T _{STG} | -65 to 150 | °C |
| Lead Temperature 1.6 mm (1/16 inch) from case for 10 seconds | T _{SLD} | 260 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect

- All voltage values, except differential voltages, are respect to GND
 Input voltage range is limited to 20V or V_{CC} +5 V whichever is smaller

ESD RATINGS

| Rating | Symbol | Value | Unit |
|------------------|--------|-------|------|
| Human Body Model | HBM | 2000 | V |
| Machine Model | MM | 200 | V |

THERMAL CHARACTERISTICS (Note 3)

| Rating | Symbol | Value | Unit |
|---|---------------|-------|------|
| Thermal Characteristics Thermal Resistance, Junction-to-Air SOIC8 | $R_{	hetaJA}$ | 176 | °C/W |

^{3.} Power dissipation must be considered to ensure the maximum junction temperature (θ_{JA}) is not exceeded.

RECOMMENDED OPERATING CONDITIONS

| Parameter | Symbol | | Min | Max | Unit |
|---------------------------------|------------------|------------------|-------|--------------------|------|
| Supply voltage | V _{DD} | Single supply | 2.7 | 16 | V |
| | | Split supply | ±1.35 | ±8 | |
| Common-mode input voltage range | V _{ICR} | | -0.1 | V _{DD} +5 | V |
| Operating free-air temperature | T _A | | - 40 | 125 | °C |

DC PERFORMANCE ELECTRICAL CHARACTERISTICS AT SPECIFIED OPERATING FREE-AIR TEMPERATURE, $V_S = 2.7 \text{ V}$, 5 V, 15 V (unless otherwise noted)

| Parameter | Symbol | Testing Conditions | T _A | Min | Тур | Max | Unit |
|---|-----------------|--|----------------|-----|------|------|-------|
| | | | 25°C | | 250 | 3600 | |
| Input offset voltage | V _{IO} | $V_{CM} = V_S/2$, $R_S = 50 \Omega$, $R_P = 1 M\Omega$ | Full range | | | 4400 | μV |
| Offset voltage drift | ΔV_{IO} | | 25°C | | 3 | | μV/°C |
| | | | 25°C | 55 | 72 | | |
| | CMRR | V_{CM} = 0 to 2.7 V, R_S = 50 Ω | Full range | 50 | | | |
| Common mode rejection | | CMRR $V_{CM} = 0 \text{ to 5 V, } R_S = 50 \Omega$ | 25°C | 60 | 76 | | |
| Common-mode rejection ratio | | | Full range | 55 | | | dB |
| | | | 25°C | 65 | 88 | | |
| | | V_{CM} = 0 to 15 V, R_S = 50 Ω | Full range | 60 | | | |
| Large-signal differential voltage amplification | A _{VD} | R_P = 1 $M\Omega$ | 25°C | | 1000 | | V/mV |

INPUT/OUTPUT CHARACTERISTICS SPECIFIED OPERATING FREE-AIR TEMPERATURE,

 $V_S = 2.7 \text{ V}, 5 \text{ V}, 15 \text{ V} \text{ (unless otherwise noted)}$

| Input offset current | | | 25°C | 20 | 100 | |
|---------------------------------------|-----------------|--|---------------|-----|------|----|
| (Note 4) | I _{IO} | V V/0 D 1 MO D 50 O | Full range | | 1000 | pA |
| Input bias current | | $V_{CM} = V_S/2$, $R_P = 1$ MΩ, $R_S = 50$ Ω | 25°C | 80 | 250 | |
| (Note 4) | I _{IB} | | Full range | | 3000 | pA |
| Differential input resistance | R _{ID} | V _{in} = V _S /2 | 25°C | 300 | | МΩ |
| High-impedance output leakage current | l _{OZ} | $V_{CM} = V_S/2, V_O = V_{CC}, V_{ID} = 1 V$ | 25°C | 50 | | рА |
| | | $V_{CM} = V_S/2$, $I_{OL} = 2 \mu A$, $V_{ID} = -1 V$ | 25°C | 8 | | |
| Low-level output voltage | V_{OL} | | 25°C | 80 | 200 | mV |
| Low level output voltage | - 0L | $V_{CM} = V_S/2$, $I_{OL} = 50 \mu A$, $V_{ID} = -1 V$ | Full range | | 300 | |

POWER SUPPLY SPECIFIED OPERATING FREE-AIR TEMPERATURE, V_{CC} = 2.7 V, 5 V, 15 V (unless otherwise noted)

| | | | | 25°C | | 470 | 550 | | | |
|------------------------|-----------|--|--------------------------------|---------------|----|------|-----|-----|--|--|
| Supply current (per | | | Output state low | Full range | | | 750 | A | | |
| channel) | Icc | R _P = No pullup | | 25°C | | 560 | 640 | nA | | |
| | | Output state high | Full range | | | 950 | | | | |
| | | | | | | 25°C | 75 | 100 | | |
| Power supply rejection | PSRR | V _{CM} = V _S /2, No load | V _{CC} = 2.7 V to 5 V | Full range | 70 | | | dB | | |
| ratio | PSHR load | load | ad | 25°C | 85 | 105 | | uБ | | |
| | | | V _{CC} = 5 V to 15 V | Full range | 80 | | | | | |

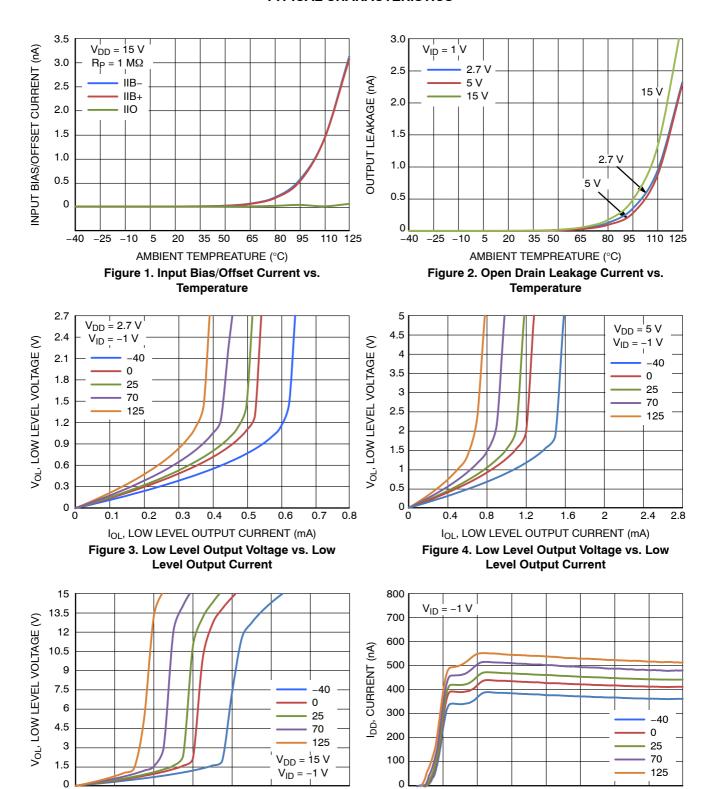
^{4.} Guaranteed by design or characterization.

SWITCHING CHARACTERISTICS AT RECOMMENDED OPERATING CONDITIONS,

 V_{CC} = 2.7 V, 5 V, 15 V, T_A = 25°C (unless otherwise noted)

| Parameter | Symbol | Testing (| Testing Conditions | | Min | Тур | Max | Unit | |
|---|--------------------|-------------------------------------|-----------------------------------|------|------|-----|-----|------|----|
| | | f = 10 kHz, VSTEP = 100 mV, | Overdrive = 2 mV | 25°C | 25°C | | 220 | | |
| Propagation delay time, low-to-high-level | t _(PLH) | | Overdrive = 10 mV | | | | 85 | | |
| to ingli level | | | Overdrive = 50 mV | | | 30 | | | |
| | | R_P = 1 $M\Omega$, C_L = 10 pF | Overdrive = 2 mV | 25°C | | | 250 | | μs |
| Propagation delay time, high-to-low-level output | t _(PHL) | | Overdrive = 10 mV | | | 55 | | | |
| | | | Overdrive = 50 mV | | | 18 | | | |
| Fall time | tf | R _P = 1 MΩ | $R_P = 1 M\Omega$, $C_L = 10 pF$ | | | 5 | | μs | |

TYPICAL CHARACTERISTICS



I_{OL}, LOW LEVEL OUTPUT CURRENT (mA)

Figure 5. Low Level Output Voltage vs. Low
Level Output Current

 $\label{eq:VDD} V_{DD} \mbox{ SUPPLY (V)}$ Figure 6. I_{DD} vs. V_{DD} vs. Temperature

8

10

14

16

6

2.8

2.4

TYPICAL CHARACTERISTICS

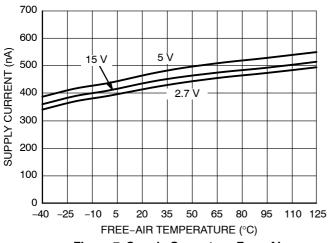


Figure 7. Supply Current vs. Free-Air **Temperature**

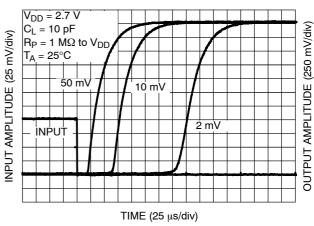
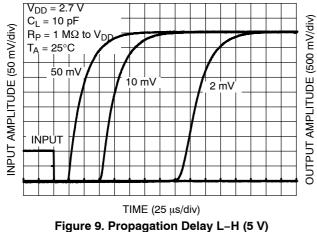


Figure 8. Propagation Delay L-H (2.7 V)



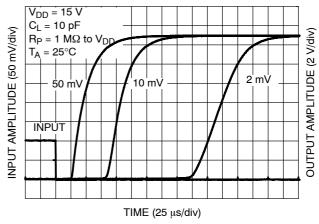


Figure 10. Propagation Delay L-H (15 V)

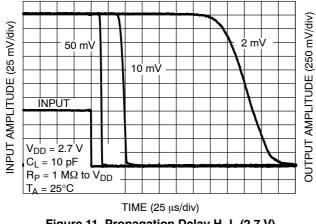


Figure 11. Propagation Delay H-L (2.7 V)

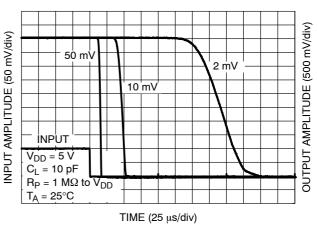


Figure 12. Propagation Delay H-L (5 V)

TYPICAL CHARACTERISTICS

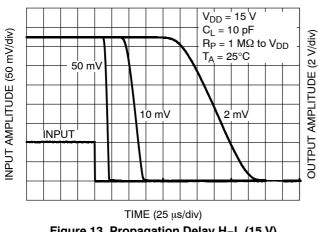


Figure 13. Propagation Delay H-L (15 V)

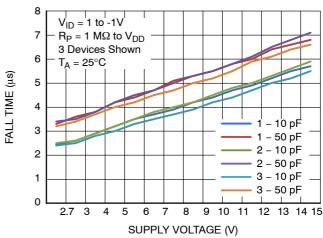


Figure 14. Output Fall Time vs. Power Supply

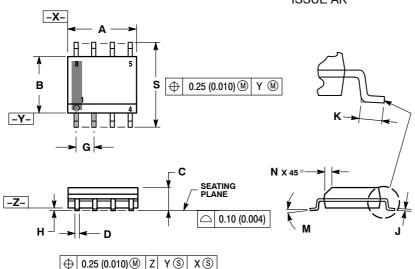
ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-------------|---------------------|-----------------------|
| NCS3402DR2G | SOIC-8 (Pb-Free) | 2500 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SOIC-8 NB CASE 751-07 **ISSUE AK**



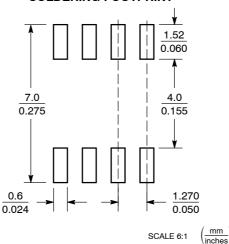
NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14 5M 1982
- CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- PER SIDE.

 DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
 751-01 THRU 751-06 ARE OBSOLETE. NEW
- STANDARD IS 751-07.

| | MILLIN | MILLIMETERS | | HES |
|-----|--------|-------------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 4.80 | 5.00 | 0.189 | 0.197 |
| В | 3.80 | 4.00 | 0.150 | 0.157 |
| С | 1.35 | 1.75 | 0.053 | 0.069 |
| D | 0.33 | 0.51 | 0.013 | 0.020 |
| G | 1.27 | 7 BSC | 0.050 BSC | |
| Η | 0.10 | 0.25 | 0.004 | 0.010 |
| 7 | 0.19 | 0.25 | 0.007 | 0.010 |
| K | 0.40 | 1.27 | 0.016 | 0.050 |
| М | 0 ° | 0 ° 8 ° | | 8 ° |
| Ν | 0.25 | 0.50 | 0.010 | 0.020 |
| s | 5.80 | 6.20 | 0.228 | 0.244 |

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SCALE 6:1

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